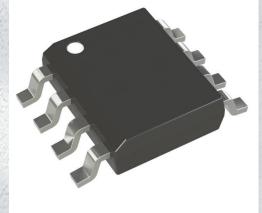


MCP6042-E/SNVAO Datasheet

www.digi-electronics.com



DiGi Electronics Part Number	MCP6042-E/SNVAO-DG
Manufacturer	Microchip Technology
Manufacturer Product Number	MCP6042-E/SNVAO
Description	IC OPAMP GP 2 CIRCUIT 8SOIC
Detailed Description	General Purpose Amplifier 2 Circuit Rail-to-Rail 8-S OIC

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Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
MCP6042-E/SNVAO	Microchip Technology
Series:	Product Status:
	Active
Amplifier Type:	Number of Circuits:
General Purpose	2
Output Type:	Slew Rate:
Rail-to-Rail	0.003V/µs
Gain Bandwidth Product:	Current - Input Bias:
14 kHz	1 pA
Voltage - Input Offset:	Current - Supply:
3 mV	600nA (x2 Channels)
Current - Output / Channel:	Voltage - Supply Span (Min):
20 mA	1.4 V
Voltage - Supply Span (Max):	Operating Temperature:
6 V	-40°C ~ 125°C (TA)
Mounting Type:	Package / Case:
Surface Mount	8-SOIC (0.154", 3.90mm Width)
Supplier Device Package:	Base Product Number:
8-SOIC	MCP6042

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	3 (168 Hours)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8542.33.0001	



600 nA, Rail-to-Rail Input/Output Op Amps

Features

- · Low Quiescent Current: 600 nA/amplifier (typical)
- Rail-to-Rail Input/Output
- Gain Bandwidth Product: 14 kHz (typical)
- Wide Supply Voltage Range: 1.4V to 6.0V
- Unity Gain Stable
- · Available in Single, Dual, and Quad
- Chip Select (CS) with MCP6043
- · Available in 5-lead and 6-lead SOT-23 Packages
- Temperature Ranges:
 - Industrial: -40°C to +85°C
 - Extended: -40°C to +125°C

Applications

- Toll Booth Tags
- Wearable Products
- Temperature Measurement
- Battery Powered

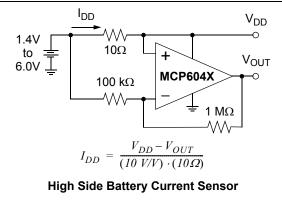
Design Aids

- · SPICE Macro Models
- FilterLab[®] Software
- MAPS (Microchip Advanced Part Selector)
- Analog Demonstration and Evaluation Boards
- · Application Notes

Related Devices

• MCP6141/2/3/4: G = +10 Stable Op Amps

Typical Application



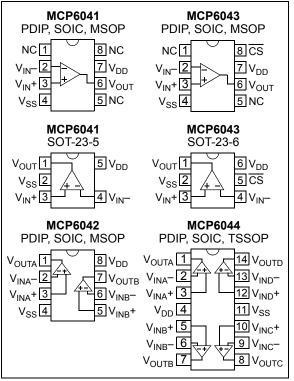
Description

The MCP6041/2/3/4 family of operational amplifiers (op amps) from Microchip Technology Inc. operate with a single supply voltage as low as 1.4V, while drawing less than 1 μ A (maximum) of quiescent current per amplifier. These devices are also designed to support rail-to-rail input and output operation. This combination of features supports battery-powered and portable applications.

The MCP6041/2/3/4 amplifiers have a gain-bandwidth product of 14 kHz (typical) and are unity gain stable. These specifications make these op amps appropriate for low frequency applications, such as battery current monitoring and sensor conditioning.

The MCP6041/2/3/4 family operational amplifiers are offered in single (MCP6041), single with Chip Select (CS) (MCP6043), dual (MCP6042), and quad (MCP6044) configurations. The MCP6041 device is available in the 5-lead SOT-23 package, and the MCP6043 device is available in the 6-lead SOT-23 package.

Package Types



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

V _{DD} – V _{SS} Current at Input Pins	
Analog Inputs (V _{IN} +, V _{IN} -) V _{SS}	
All Other Inputs and Outputs V _{SS}	-0.3V to V _{DD} + 0.3V
Difference Input voltage	V _{DD} – V _{SS}
Output Short Circuit Current	continuous
Current at Output and Supply Pins	±30 mA
Storage Temperature	–65°C to +150°C
Junction Temperature	+150°C
ESD protection on all pins (HBM; MM).	≥ 4 kV; 200V

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

++ See Section 4.1 "Rail-to-Rail Input"

DC ELECTRICAL CHARACTERISTICS

Electrical Characteristics: Unless otherwise indicated, V _{DD} = +1.4V to +5.5V, V _{SS} = GND, T _A = 25°C, V _{CM} = V _{DD} /2,
$V_{OUT} \approx V_{DD}/2$, $V_{I} = V_{DD}/2$, and $R_{I} = 1 M\Omega$ to V_{I} (refer to Figure 1-2 and Figure 1-3).

Parameters	Sym	Min	Тур	Max	Units	Conditions
Input Offset						·
Input Offset Voltage	V _{OS}	-3		+3	mV	V _{CM} = V _{SS}
Drift with Temperature	$\Delta V_{OS} / \Delta T_A$	_	±2	—	μV/°C	$V_{CM} = V_{SS}, T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$
	$\Delta V_{OS} / \Delta T_A$	—	±15	—	µV/°C	$V_{CM} = V_{SS},$ $T_A = +85^{\circ}C$ to +125°C
Power Supply Rejection	PSRR	70	85	—	dB	V _{CM} = V _{SS}
Input Bias Current and Impedance						
Input Bias Current	Ι _Β	_	1	—	pА	
Industrial Temperature	I _B	—	20	100	pА	T _A = +85°
Extended Temperature	Ι _Β	—	1200	5000	pА	T _A = +125°
Input Offset Current	I _{OS}	—	1	—	pА	
Common-mode Input Impedance	Z _{CM}	—	10 ¹³ 6	—	Ω pF	
Differential Input Impedance	Z _{DIFF}	—	10 ¹³ 6	—	Ω pF	
Common-mode						
Common-mode Input Range	V _{CMR}	V _{SS} -0.3	—	V _{DD} +0.3	V	
Common-mode Rejection Ratio	CMRR	62	80	—	dB	V_{DD} = 5V, V_{CM} = -0.3V to 5.3V
	CMRR	60	75	—	dB	V_{DD} = 5V, V_{CM} = 2.5V to 5.3V
	CMRR	60	80	—	dB	V_{DD} = 5V, V_{CM} = -0.3V to 2.5V
Open-Loop Gain						
DC Open-Loop Gain (large signal)	A _{OL}	95	115	—	dB	R_L = 50 kΩ to V _L , V _{OUT} = 0.1V to V _{DD} -0.1V
Output						
Maximum Output Voltage Swing	V _{OL} , V _{OH}	V _{SS} + 10	_	V _{DD} – 10	mV	$R_L = 50 k\Omega$ to V_L , 0.5V input overdrive
Linear Region Output Voltage Swing	V _{OVR}	V _{SS} + 100	—	V _{DD} - 100	mV	$\label{eq:RL} \begin{array}{l} \textbf{R}_L = 50 \ \textbf{k} \Omega \ \text{to} \ \textbf{V}_L, \\ \textbf{A}_{OL} \geq 95 \ \textbf{dB} \end{array}$
Output Short Circuit Current	I _{SC}	—	2	—	mA	V _{DD} = 1.4V
	I _{SC}	—	20	—	mA	V _{DD} = 5.5V
Power Supply						
Supply Voltage	V _{DD}	1.4		6.0	V	(Note 1)
Quiescent Current per Amplifier	ا _Q	0.3	0.6	1.0	μA	I _O = 0

Note 1: All parts with date codes November 2007 and later have been screened to ensure operation at V_{DD} = 6.0V. However, the other minimum and maximum specifications are measured at 1.4V and/or 5.5V.

AC ELECTRICAL CHARACTERISTICS

$V_{OUT} \approx V_{DD}/2$, $V_L = V_{DD}/2$, $R_L = 1 \text{ M}\Omega$ to V_L , and $C_L = 60 \text{ pF}$ (refer to Figure 1-2 and Figure 1-3).									
Parameters	Sym	Min	Тур	Мах	Units	Conditions			
AC Response									
Gain Bandwidth Product	GBWP	_	14	_	kHz				
Slew Rate	SR	_	3.0	_	V/ms				
Phase Margin	PM	_	65	_	٥	G = +1 V/V			
Noise									
Input Voltage Noise	E _{ni}	_	5.0		μV _{P-P}	f = 0.1 Hz to 10 Hz			
Input Voltage Noise Density	e _{ni}	_	170		nV/√Hz	f = 1 kHz			
Input Current Noise Density	i _{ni}	_	0.6		fA/√Hz	f = 1 kHz			

MCP6043 CHIP SELECT (CS) ELECTRICAL CHARACTERISTICS

Parameters	Sym	Min	Тур	Max	Units	Conditions				
CS Low Specifications										
CS Logic Threshold, Low	VIL	V _{SS}	_	V _{SS} +0.3	V					
CS Input Current, Low	I _{CSL}		5	_	pА	$\overline{\text{CS}} = V_{\text{SS}}$				
CS High Specifications										
CS Logic Threshold, High	V_{IH}	V _{DD} -0.3	_	V _{DD}	V					
CS Input Current, High	I _{CSH}		5	_	pА	$\overline{\text{CS}} = \text{V}_{\text{DD}}$				
CS Input High, GND Current	I _{SS}		-20	_	pА	$\overline{\text{CS}} = \text{V}_{\text{DD}}$				
Amplifier Output Leakage, CS High	I _{OLEAK}	_	20	_	pА	$\overline{\text{CS}} = \text{V}_{\text{DD}}$				
Dynamic Specifications										
CS Low to Amplifier Output Turn-on Time	t _{ON}	—	2	50	ms	G = +1V/V, \overline{CS} = 0.3V to V _{OUT} = 0.9V _{DD} /2				
CS High to Amplifier Output High-Z	t _{OFF}	_	10	_	μs	G = +1V/V, \overline{CS} = V _{DD} -0.3V to V _{OUT} = 0.1V _{DD} /2				
Hysteresis	V _{HYST}	—	0.6	_	V	V _{DD} = 5.0V				

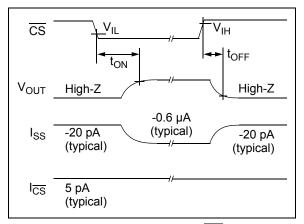


FIGURE 1-1: Chip Select $\overline{(CS)}$ Timing Diagram (MCP6043 only).

TEMPERATURE CHARACTERISTICS

Electrical Characteristics: Unless otherwise indicated, V _{DD} = +1.4V to +5.5V, V _{SS} = GND.									
Parameters	Sym	Min	Тур	Мах	Units	Conditions			
Temperature Ranges									
Specified Temperature Range	T _A	-40	_	+85	°C	Industrial Temperature parts			
	T _A	-40	_	+125	°C	Extended Temperature parts			
Operating Temperature Range	T _A	-40	_	+125	°C	(Note 1)			
Storage Temperature Range	Τ _Α	-65	_	+150	°C				
Thermal Package Resistances									
Thermal Resistance, 5L-SOT-23	θ_{JA}	_	256		°C/W				
Thermal Resistance, 6L-SOT-23	θ_{JA}	_	230	_	°C/W				
Thermal Resistance, 8L-PDIP	θ_{JA}	_	85		°C/W				
Thermal Resistance, 8L-SOIC	θ_{JA}	_	163		°C/W				
Thermal Resistance, 8L-MSOP	θ_{JA}	_	206	_	°C/W				
Thermal Resistance, 14L-PDIP	θ_{JA}		70	_	°C/W				
Thermal Resistance, 14L-SOIC	θ_{JA}		120	_	°C/W				
Thermal Resistance, 14L-TSSOP	θ_{JA}	_	100	—	°C/W				

Note 1: The MCP6041/2/3/4 family of Industrial Temperature op amps operates over this extended range, but with reduced performance. In any case, the internal Junction Temperature (T_J) must not exceed the Absolute Maximum specification of +150°C.

1.1 Test Circuits

The test circuits used for the DC and AC tests are shown in Figure 1-2 and Figure 1-3. The bypass capacitors are laid out according to the rules discussed in **Section 4.6 "Supply Bypass"**.

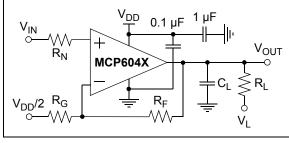


FIGURE 1-2: AC and DC Test Circuit for Most Non-Inverting Gain Conditions.

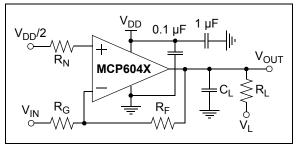


FIGURE 1-3: AC and DC Test Circuit for Most Inverting Gain Conditions.

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated, $T_A = +25^{\circ}C$, $V_{DD} = +1.4V$ to +6.0V, $V_{SS} = GND$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $V_L = V_{DD}/2$, $R_L = 1 M\Omega$ to V_L , and $C_L = 60 \text{ pF}$.

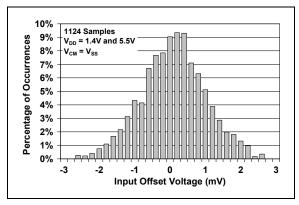


FIGURE 2-1:

Input Offset Voltage.

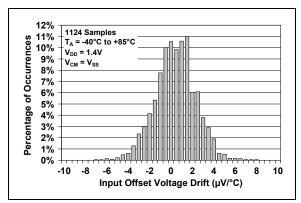


FIGURE 2-2: Input Offset Voltage Drift with $T_A = -40^{\circ}$ C to $+85^{\circ}$ C.

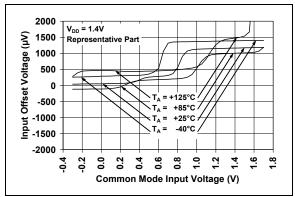


FIGURE 2-3: Input Offset Voltage vs. Common-mode Input Voltage with $V_{DD} = 1.4V$.

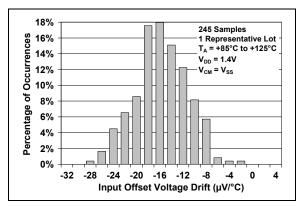


FIGURE 2-4: Input Offset Voltage Drift with $T_A = +85^{\circ}$ C to $+125^{\circ}$ C and $V_{DD} = 1.4V$.

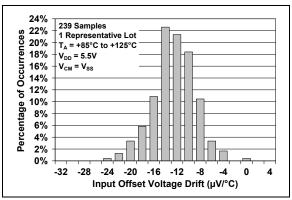


FIGURE 2-5: Input Offset Voltage Drift with $T_A = +25^{\circ}$ C to $+125^{\circ}$ C and $V_{DD} = 5.5V$.

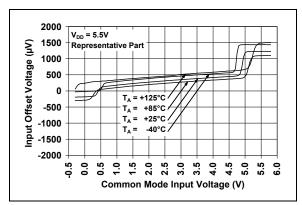
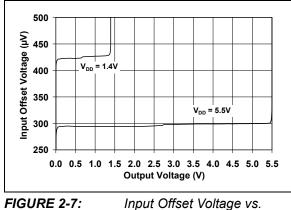


FIGURE 2-6: Input Offset Voltage vs. Common-mode Input Voltage with $V_{DD} = 5.5V$.

Note: Unless otherwise indicated, $T_A = +25^{\circ}C$, $V_{DD} = +1.4V$ to +6.0V, $V_{SS} = GND$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $V_L = V_{DD}/2$, $R_L = 1 M\Omega$ to V_L , and $C_L = 60 \text{ pF}$.





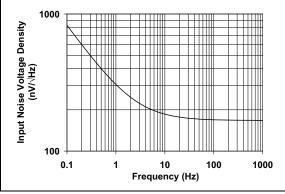


FIGURE 2-8: Input Noise Voltage Density vs. Frequency.

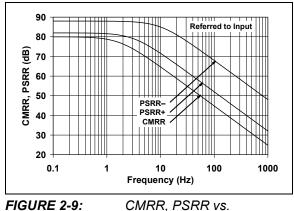


FIGURE 2-9: Frequency.

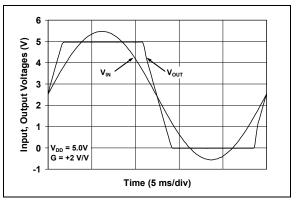


FIGURE 2-10: The MCP6041/2/3/4 family shows no phase reversal.

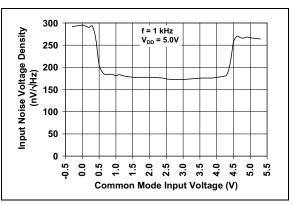


FIGURE 2-11: Input Noise Voltage Density vs. Common-mode Input Voltage.

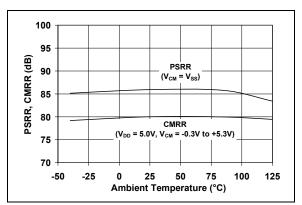


FIGURE 2-12: CMRR, PSRR vs. Ambient Temperature.

Note: Unless otherwise indicated, $T_A = +25^{\circ}C$, $V_{DD} = +1.4V$ to +6.0V, $V_{SS} = GND$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $V_L = V_{DD}/2$, $R_L = 1 M\Omega$ to V_L , and $C_L = 60 \text{ pF}$.

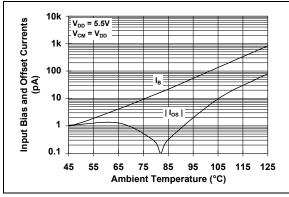


FIGURE 2-13: Input Bias, Offset Currents vs. Ambient Temperature.

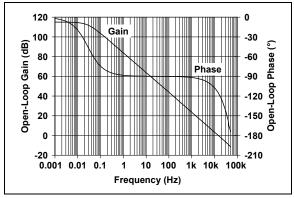


FIGURE 2-14: Open-Loop Gain, Phase vs. Frequency.

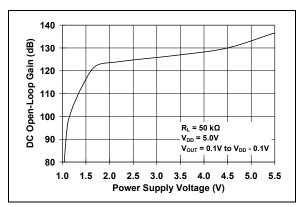


FIGURE 2-15: DC Open-Loop Gain vs. Power Supply Voltage.

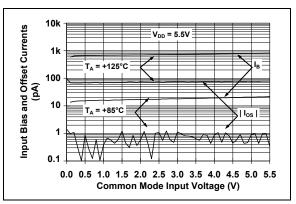


FIGURE 2-16: Input Bias, Offset Currents vs. Common-mode Input Voltage.

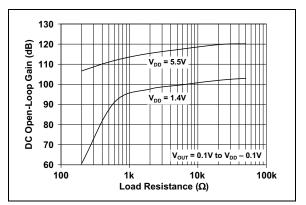


FIGURE 2-17: DC Open-Loop Gain vs. Load Resistance.

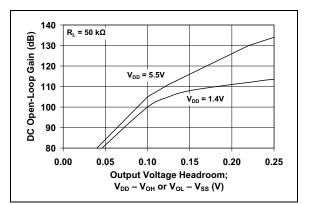


FIGURE 2-18: DC Open-Loop Gain vs. Output Voltage Headroom.

Note: Unless otherwise indicated, $T_A = +25^{\circ}$ C, $V_{DD} = +1.4$ V to +6.0V, $V_{SS} = GND$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $V_L = V_{DD}/2$, $R_L = 1 \text{ M}\Omega$ to V_L , and $C_L = 60 \text{ pF}$.

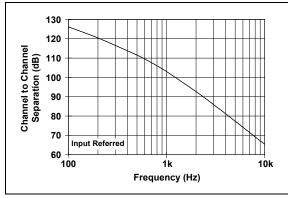


FIGURE 2-19: Channel-to-Channel Separation vs. Frequency (MCP6042 and MCP6044 only).

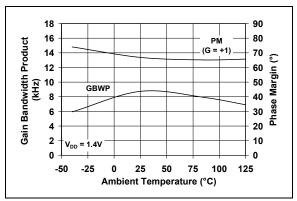


FIGURE 2-20: Gain Bandwidth Product, Phase Margin vs. Ambient Temperature with $V_{DD} = 1.4V$.

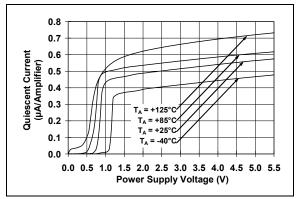


FIGURE 2-21: Quiescent Current vs. Power Supply Voltage.

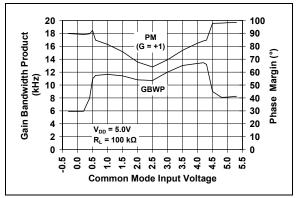


FIGURE 2-22: Gain Bandwidth Product, Phase Margin vs. Common-mode Input Voltage.

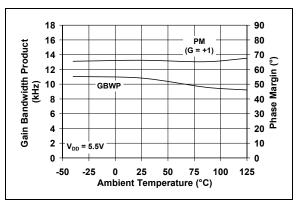


FIGURE 2-23: Gain Bandwidth Product, Phase Margin vs. Ambient Temperature with $V_{DD} = 5.5V$.

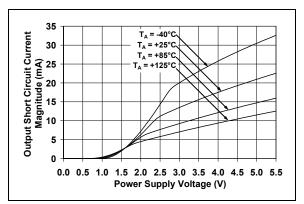


FIGURE 2-24: Output Short Circuit Current vs. Power Supply Voltage.

Note: Unless otherwise indicated, $T_A = +25^{\circ}C$, $V_{DD} = +1.4V$ to +6.0V, $V_{SS} = GND$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $V_L = V_{DD}/2$, $R_L = 1 M\Omega$ to V_L , and $C_L = 60 \text{ pF}$.

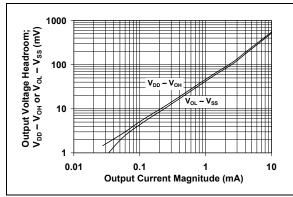


FIGURE 2-25: Output Voltage Headroom vs. Output Current Magnitude.

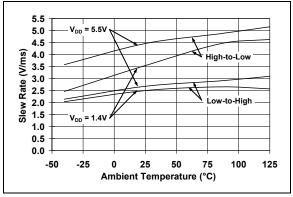


FIGURE 2-26: Slew Rate vs. Ambient Temperature.

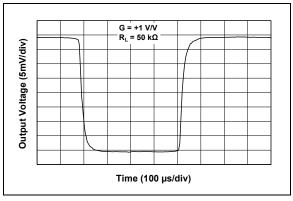


FIGURE 2-27: Pulse Response.

Small Signal Non-inverting

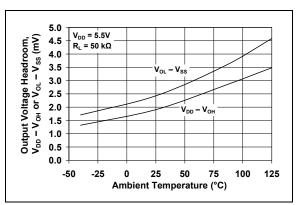


FIGURE 2-28: Output Voltage Headroom vs. Ambient Temperature.

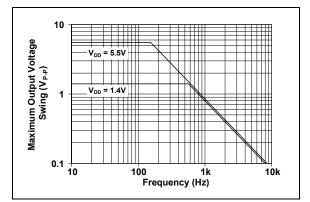


FIGURE 2-29: Maximum Output Voltage Swing vs. Frequency.

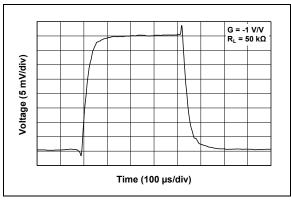


FIGURE 2-30: Sm. Response.

Small Signal Inverting Pulse

Note: Unless otherwise indicated, $T_A = +25^{\circ}$ C, $V_{DD} = +1.4$ V to +6.0V, $V_{SS} = GND$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $V_L = V_{DD}/2$, $R_L = 1 M\Omega$ to V_L , and $C_L = 60$ pF.

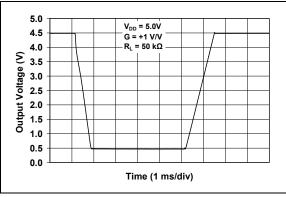


FIGURE 2-31: Large Signal Non-inverting Pulse Response.

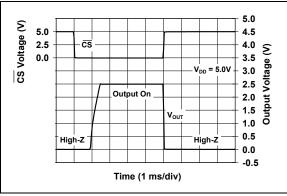


FIGURE 2-32: Chip Select (\overline{CS}) to Amplifier Output Response Time (MCP6043 only).

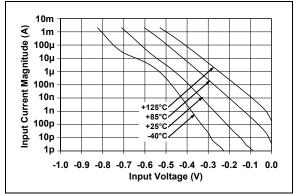


FIGURE 2-33: Input Current vs. Input Voltage (below V_{SS}).

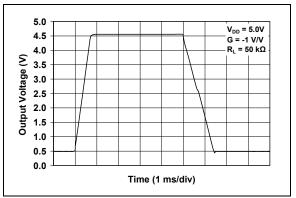


FIGURE 2-34: Large Signal Inverting Pulse Response.

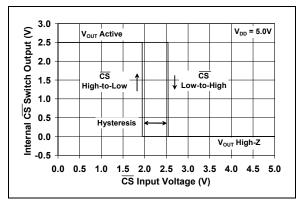


FIGURE 2-35: Chip Select (\overline{CS}) Hysteresis (MCP6043 only).

3.0 PIN DESCRIPTIONS

Descriptions of the pins are listed in Table 3-1.

М	CP6041	MCP6042	М	CP6043	MCP6044		
PDIP, SOIC, MSOP	SOT-23-5	PDIP, SOIC, MSOP	PDIP, SOIC, MSOP	SOT-23-6	PDIP, SOIC, TSSOP	Symbol	Description
6	1	1	6	1	1	V _{OUT} , V _{OUTA}	Analog Output (op amp A)
2	4	2	2	4	2	V _{IN} –, V _{INA} –	Inverting Input (op amp A)
3	3	3	3	3	3	V _{IN} +, V _{INA} +	Non-inverting Input (op amp A)
7	5	8	7	6	4	V _{DD}	Positive Power Supply
—	_	5	_	_	5	V _{INB} +	Non-inverting Input (op amp B)
—	—	6	_	_	6	V _{INB} –	Inverting Input (op amp B)
—	_	7	_	_	7	V _{OUTB}	Analog Output (op amp B)
_	_	—	_	_	8	V _{OUTC}	Analog Output (op amp C)
—	—	—	_	_	9	V _{INC} -	Inverting Input (op amp C)
_	_	—	_	_	10	V _{INC} +	Non-inverting Input (op amp C)
4	2	4	4	2	11	V _{SS}	Negative Power Supply
	_	—	_	_	12	V _{IND} +	Non-inverting Input (op amp D)
_	_	—	_	_	13	V _{IND} -	Inverting Input (op amp D)
—	_	—	_	_	14	V _{OUTD}	Analog Output (op amp D)
_	_	_	8	5	_	CS	Chip Select
1, 5, 8		_	1, 5		—	NC	No Internal Connection

TABLE 3-1: PIN FUNCTION TABLE

3.1 Analog Outputs

The output pins are low-impedance voltage sources.

3.2 Analog Inputs

The non-inverting and inverting inputs are high-impedance CMOS inputs with low bias currents.

3.3 Chip Select Digital Input

This is a CMOS, Schmitt-triggered input that places the part into a low power mode of operation.

3.4 Power Supply Pins

The positive power supply pin (V_{DD}) is 1.4V to 6.0V higher than the negative power supply pin (V_{SS}). For normal operation, the other pins are at voltages between V_{SS} and V_{DD}.

Typically, these parts are used in a single (positive) supply configuration. In this case, V_{SS} is connected to ground and V_{DD} is connected to the supply. V_{DD} will need bypass capacitors.

NOTES:

4.0 APPLICATIONS INFORMATION

The MCP6041/2/3/4 family of op amps is manufactured using Microchip's state of the art CMOS process. These op amps are unity gain stable and suitable for a wide range of general purpose, low-power applications.

See Microchip's related MCP6141/2/3/4 family of op amps for applications, at a gain of 10 V/V or higher, needing greater bandwidth.

4.1 Rail-to-Rail Input

4.1.1 PHASE REVERSAL

The MCP6041/2/3/4 op amps are designed to not exhibit phase inversion when the input pins exceed the supply voltages. Figure 2-10 shows an input voltage exceeding both supplies with no phase inversion.

4.1.2 INPUT VOLTAGE AND CURRENT LIMITS

The ESD protection on the inputs can be depicted as shown in Figure 4-1. This structure was chosen to protect the input transistors, and to minimize input bias current (I_B). The input ESD diodes clamp the inputs when they try to go more than one diode drop below V_{SS} . They also clamp any voltages that go too far above V_{DD} ; their breakdown voltage is high enough to allow normal operation, and low enough to bypass quick ESD events within the specified limits.

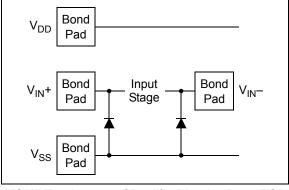


FIGURE 4-1: Simplified Analog Input ESD Structures.

In order to prevent damage and/or improper operation of these amplifiers, the circuit must limit the currents (and voltages) at the input pins (see Absolute Maximum Ratings † at the beginning of Section 1.0 "Electrical Characteristics"). Figure 4-2 shows the recommended approach to protecting these inputs. The internal ESD diodes prevent the input pins (V_{IN}^+ and V_{IN}^-) from going too far below ground, and the resistors R_1 and R_2 limit the possible current drawn out of the input pins. Diodes D_1 and D_2 prevent the input pins (V_{IN}^+ and V_{IN}^-) from going too far above V_{DD} , and

dump any currents onto V_{DD} . When implemented as shown, resistors R_1 and R_2 also limit the current through D_1 and D_2 .

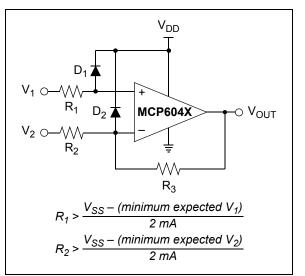


FIGURE 4-2: Protecting the Analog Inputs.

It is also possible to connect the diodes to the left of the resistor R₁ and R₂. In this case, the currents through the diodes D₁ and D₂ need to be limited by some other mechanism. The resistors then serve as in-rush current limiters; the DC current into the input pins (V_{IN}+ and V_{IN}-) should be very small.

A significant amount of current can flow out of the inputs (through the ESD diodes) when the Commonmode voltage (V_{CM}) is below ground (V_{SS}); see Figure 2-33. Applications that are high impedance may need to limit the useable voltage range.

4.1.3 NORMAL OPERATION

The input stage of the MCP6041/2/3/4 op amps uses two differential input stages in parallel. One operates at a low Common-mode input voltage (V_{CM}), while the other operates at a high V_{CM}. With this topology, the device operates with a V_{CM} up to 300 mV above V_{DD} and 300 mV below V_{SS}. The input offset voltage is measured at V_{CM} = V_{SS} - 0.3V and V_{DD} + 0.3V to ensure proper operation.

There are two transitions in input behavior as V_{CM} is changed. The first occurs, when V_{CM} is near V_{SS} + 0.4V, and the second occurs when V_{CM} is near V_{DD} – 0.5V (see Figure 2-3 and Figure 2-6). For the best distortion performance with non-inverting gains, avoid these regions of operation.

4.2 Rail-to-Rail Output

There are two specifications that describe the output swing capability of the MCP6041/2/3/4 family of op amps. The first specification (Maximum Output Voltage Swing) defines the absolute maximum swing that can be achieved under the specified load condition. Thus, the output voltage swings to within 10 mV of either supply rail with a 50 k Ω load to V_{DD}/2. Figure 2-10 shows how the output voltage is limited when the input goes beyond the linear region of operation.

The second specification that describes the output swing capability of these amplifiers is the Linear Output Voltage Range. This specification defines the maximum output swing that can be achieved while the amplifier still operates in its linear region. To verify linear operation in this range, the large signal DC Open-Loop Gain (A_{OL}) is measured at points inside the supply rails. The measurement must meet the specified A_{OL} condition in the specification table.

4.3 Output Loads and Battery Life

The MCP6041/2/3/4 op amp family has outstanding quiescent current, which supports battery-powered applications. There is minimal quiescent current glitching when Chip Select (CS) is raised or lowered. This prevents excessive current draw, and reduced battery life, when the part is turned off or on.

Heavy resistive loads at the output can cause excessive battery drain. Driving a DC voltage of 2.5V across a 100 k Ω load resistor will cause the supply current to increase by 25 μ A, depleting the battery 43 times as fast as I_Q (0.6 μ A, typical) alone.

High frequency signals (fast edge rate) across capacitive loads will also significantly increase supply current. For instance, a 0.1 μ F capacitor at the output presents an AC impedance of 15.9 k Ω (1/2 π fC) to a 100 Hz sinewave. It can be shown that the average power drawn from the battery by a 5.0 V_{p-p} sinewave (1.77 V_{rms}), under these conditions, is

EQUATION 4-1:

$$P_{Supply} = (V_{DD} - V_{SS}) (I_Q + V_{L(p-p)} f C_L)$$

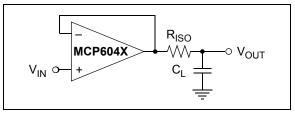
= (5V)(0.6 \mu A + 5.0V_{p-p} • 100Hz • 0.1\mu F)
= 3.0 \mu W + 50 \mu W

This will drain the battery 18 times as fast as I_{Q} alone.

4.4 Capacitive Loads

Driving large capacitive loads can cause stability problems for voltage feedback op amps. As the load capacitance increases, the feedback loop's phase margin decreases and the closed-loop bandwidth is reduced. This produces gain peaking in the frequency response, with overshoot and ringing in the step response. A unity gain buffer (G = +1) is the most sensitive to capacitive loads, although all gains show the same general behavior.

When driving large capacitive loads with these op amps (e.g., > 60 pF when G = +1), a small series resistor at the output (R_{ISO} in Figure 4-3) improves the feedback loop's phase margin (stability) by making the output load resistive at higher frequencies. The bandwidth will be generally lower than the bandwidth with no capacitive load.



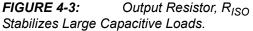


Figure 4-4 gives recommended R_{ISO} values for different capacitive loads and gains. The x-axis is the normalized load capacitance (C_L/G_N), where G_N is the circuit's noise gain. For non-inverting gains, G_N and the Signal Gain are equal. For inverting gains, G_N is 1+|Signal Gain| (e.g., -1 V/V gives G_N = +2 V/V).

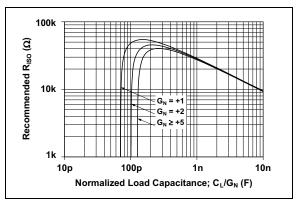


FIGURE 4-4: Recommended R_{ISO} Values for Capacitive Loads.

After selecting R_{ISO} for your circuit, double check the resulting frequency response peaking and step response overshoot. Modify R_{ISO} 's value until the response is reasonable. Bench evaluation and simulations with the MCP6041/2/3/4 SPICE macro model are helpful.

4.5 MCP6043 Chip Select

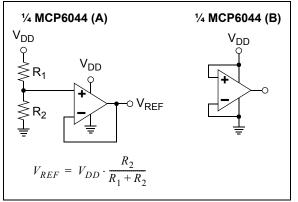
The MCP6043 is a single op amp with Chip Select (CS). When CS is pulled high, the supply current drops to 50 nA (typical) and flows through the CS pin to V_{SS} . When this happens, the amplifier output is put into a high impedance state. By pulling CS low, the amplifier is enabled. If the CS pin is left floating, the amplifier may not operate properly. Figure 1-1 shows the output voltage and supply current response to a CS pulse.

4.6 Supply Bypass

With this family of operational amplifiers, the power supply pin (V_{DD} for single supply) should have a local bypass capacitor (i.e., 0.01 µF to 0.1 µF) within 2 mm for good high frequency performance. It can use a bulk capacitor (i.e., 1 µF or larger) within 100 mm to provide large, slow currents. This bulk capacitor is not required for most applications and can be shared with nearby analog parts.

4.7 Unused Op Amps

An unused op amp in a quad package (MCP6044) should be configured as shown in Figure 4-5. These circuits prevent the output from toggling and causing crosstalk. Circuit A sets the op amp at its minimum noise gain. The resistor divider produces any desired reference voltage within the output voltage range of the op amp; the op amp buffers that reference voltage. Circuit B uses the minimum number of components and operates as a comparator, but it may draw more current.





4.8 PCB Surface Leakage

In applications where low input bias current is critical, printed circuit board (PCB) surface leakage effects need to be considered. Surface leakage is caused by humidity, dust or other contamination on the board. Under low humidity conditions, a typical resistance between nearby traces is $10^{12}\Omega$. A 5V difference would cause 5 pA of current to flow, which is greater than the MCP6041/2/3/4 family's bias current at +25°C (1 pA, typical).

The easiest way to reduce surface leakage is to use a guard ring around sensitive pins (or traces). The guard ring is biased at the same voltage as the sensitive pin. Figure 4-6 shows an example of this type of layout.

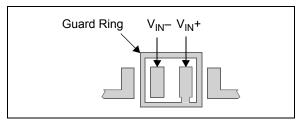


FIGURE 4-6: Example Guard Ring Layout for Inverting Gain.

- 1. Non-inverting Gain and Unity Gain Buffer:
 - a) Connect the non-inverting pin (V_{IN}+) to the input with a wire that does not touch the PCB surface.
 - b) Connect the guard ring to the inverting input pin (V_{IN}-). This biases the guard ring to the Common-mode input voltage.
- 2. Inverting Gain and Transimpedance Gain (convert current to voltage, such as photo detectors) amplifiers:
 - a) Connect the guard ring to the non-inverting input pin (V_{IN}+). This biases the guard ring to the same reference voltage as the op amp (e.g., V_{DD}/2 or ground).
 - b) Connect the inverting pin (V_{IN}-) to the input with a wire that does not touch the PCB surface.

4.9 Application Circuits

4.9.1 BATTERY CURRENT SENSING

The MCP6041/2/3/4 op amps' Common-mode Input Range, which goes 0.3V beyond both supply rails, supports their use in high-side and low-side battery current sensing applications. The very low quiescent current (0.6 μ A, typical) helps prolong battery life, and the rail-to-rail output supports detection low currents.

Figure 4-7 shows a high-side battery current sensor circuit. The 10 Ω resistor is sized to minimize power losses. The battery current (I_{DD}) through the 10 Ω resistor causes its top terminal to be more negative than the bottom terminal. This keeps the Common-mode input voltage of the op amp below V_{DD}, which is within its allowed range. The output of the op amp will also be below V_{DD}, which is within its Maximum Output Voltage Swing specification.

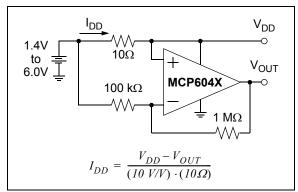


FIGURE 4-7: High-Side Battery Current Sensor.

4.9.2 INSTRUMENTATION AMPLIFIER

The MCP6041/2/3/4 op amp is well suited for conditioning sensor signals in battery-powered applications. Figure 4-8 shows a two op amp instrumentation amplifier, using the MCP6042, that works well for applications requiring rejection of Common-mode noise at higher gains. The reference voltage (V_{REF}) is supplied by a low impedance source. In single supply applications, V_{REF} is typically $V_{DD}/2$.

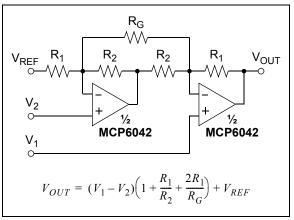


FIGURE 4-8: Two Op Amp Instrumentation Amplifier.

5.0 DESIGN AIDS

Microchip provides the basic design tools needed for the MCP6041/2/3/4 family of op amps.

5.1 SPICE Macro Model

The latest SPICE macro model for the MCP6041/2/3/4 op amps is available on the Microchip web site at www.microchip.com. This model is intended to be an initial design tool that works well in the op amp's linear region of operation over the temperature range. See the model file for information on its capabilities.

Bench testing is a very important part of any design and cannot be replaced with simulations. Also, simulation results using this macro model need to be validated by comparing them to the data sheet specifications and characteristic curves.

5.2 FilterLab[®] Software

Microchip's FilterLab[®] software is an innovative software tool that simplifies analog active filter (using op amps) design. Available at no cost from the Microchip web site at www.microchip.com/filterlab, the FilterLab design tool provides full schematic diagrams of the filter circuit with component values. It also outputs the filter circuit in SPICE format, which can be used with the macro model to simulate actual filter performance.

5.3 MAPS (Microchip Advanced Part Selector)

MAPS is a software tool that helps semiconductor professionals efficiently identify Microchip devices that fit a particular design requirement. Available at no cost from the Microchip website at www.microchip.com/ maps, the MAPS is an overall selection tool for Microchip's product portfolio that includes Analog, Memory, MCUs and DSCs. Using this tool you can define a filter to sort features for a parametric search of devices and export side-by-side technical comparison reports. Helpful links are also provided for data sheets, purchase, and sampling of Microchip parts.

5.4 Analog Demonstration and Evaluation Boards

Microchip offers a broad spectrum of Analog Demonstration and Evaluation Boards that are designed to help you achieve faster time to market. For a complete listing of these boards and their corresponding user's guides and technical information, visit the Microchip web site at www.microchip.com/ analogtools.

Some boards that are especially useful are:

- **P/N SOIC8EV:** 8-Pin SOIC/MSOP/TSSOP/DIP Evaluation Board
- P/N SOIC14EV: 14-Pin SOIC/TSSOP/DIP Evaluation Board
- MCP6XXX Amplifier Evaluation Board 1
- MCP6XXX Amplifier Evaluation Board 2
- MCP6XXX Amplifier Evaluation Board 3
- MCP6XXX Amplifier Evaluation Board 4
- · Active Filter Demo Board Kit

5.5 Application Notes

The following Microchip Application Notes are available on the Microchip web site at www.microchip.com/ appnotes and are recommended as supplemental reference resources:

ADN003: "Select the Right Operational Amplifier for your Filtering Circuits," DS21821

AN722: "Operational Amplifier Topologies and DC Specifications," DS00722

AN723: "Operational Amplifier AC Specifications and Applications," DS00723

AN884: "Driving Capacitive Loads With Op Amps," DS00884

AN990: *"Analog Sensor Conditioning Circuits – An Overview,"* DS00990

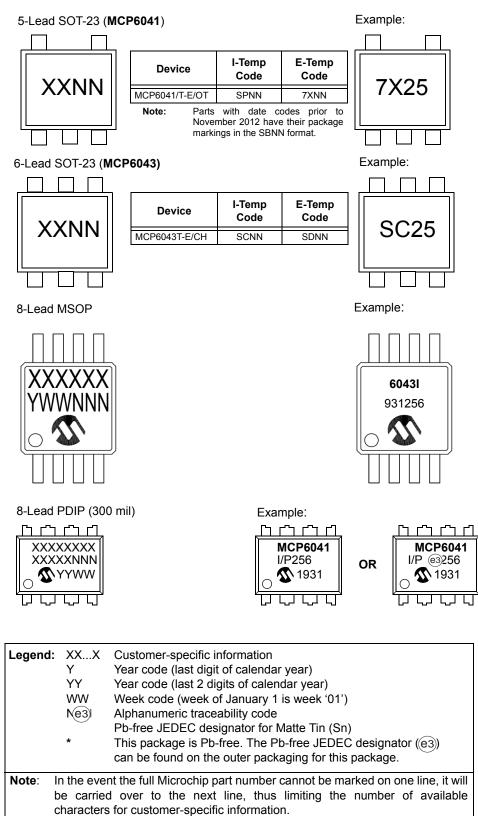
These application notes and others are listed in the design guide:

"Signal Chain Design Guide," DS21825

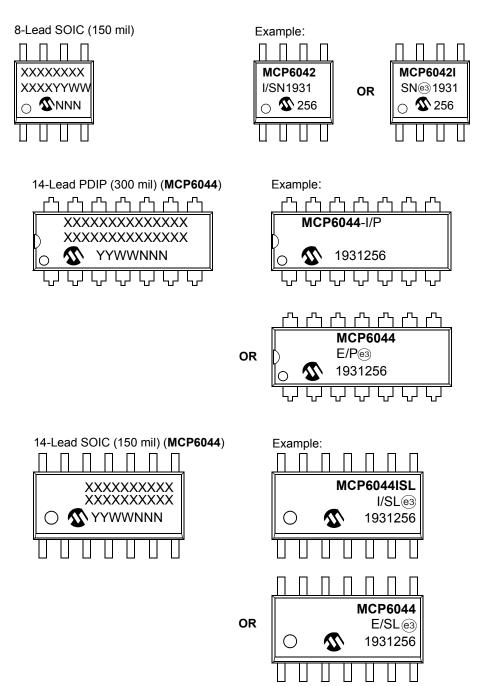
NOTES:

6.0 PACKAGING INFORMATION

6.1 Package Marking Information



Package Marking Information (Continued)



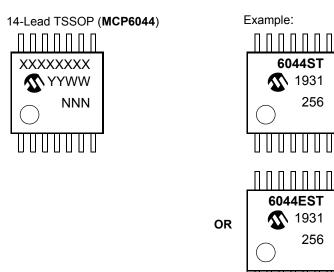
6044ST **1931**

256

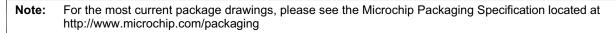
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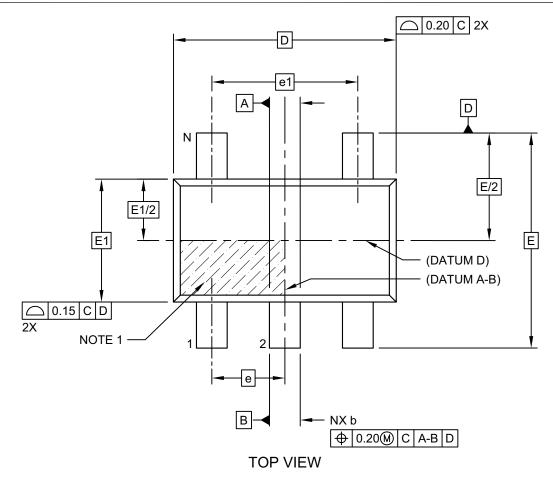
6044EST **1**931

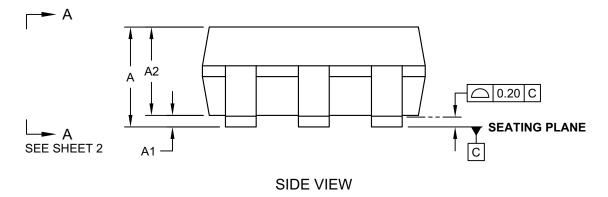
Package Marking Information (Continued)



5-Lead Plastic Small Outline Transistor (OT) [SOT23]



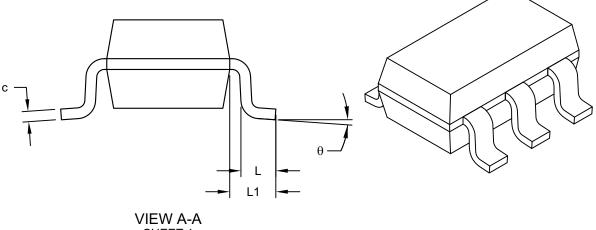




Microchip Technology Drawing C04-091-OT Rev E Sheet 1 of 2

5-Lead Plastic Small Outline Transistor (OT) [SOT23]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



SHEET 1

	MILLIMETERS				
Dimension I	Limits	MIN	NOM	MAX	
Number of Pins	Ν		5		
Pitch	е		0.95 BSC		
Outside lead pitch	e1		1.90 BSC		
Overall Height	Α	0.90	-	1.45	
Molded Package Thickness	A2	0.89	-	1.30	
Standoff	A1	-	-	0.15	
Overall Width	E	2.80 BSC			
Molded Package Width	E1	1.60 BSC			
Overall Length	D	2.90 BSC			
Foot Length	L	0.30	-	0.60	
Footprint	L1	0.60 REF			
Foot Angle	¢	0°	-	10°	
Lead Thickness	С	0.08	-	0.26	
Lead Width	b	0.20	-	0.51	

Notes:

1. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.25mm per side.

2. Dimensioning and tolerancing per ASME Y14.5M

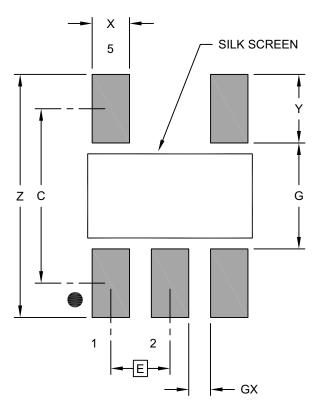
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-091-OT Rev E Sheet 2 of 2

5-Lead Plastic Small Outline Transistor (OT) [SOT23]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS			
Dimension Limits		MIN	NOM	MAX	
Contact Pitch	E 0.95 BSC				
Contact Pad Spacing	С		2.80		
Contact Pad Width (X5)	Х			0.60	
Contact Pad Length (X5)	Y			1.10	
Distance Between Pads	G	1.70			
Distance Between Pads	GX	0.35			
Overall Width	Z			3.90	

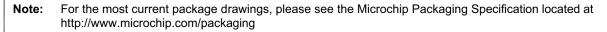
Notes:

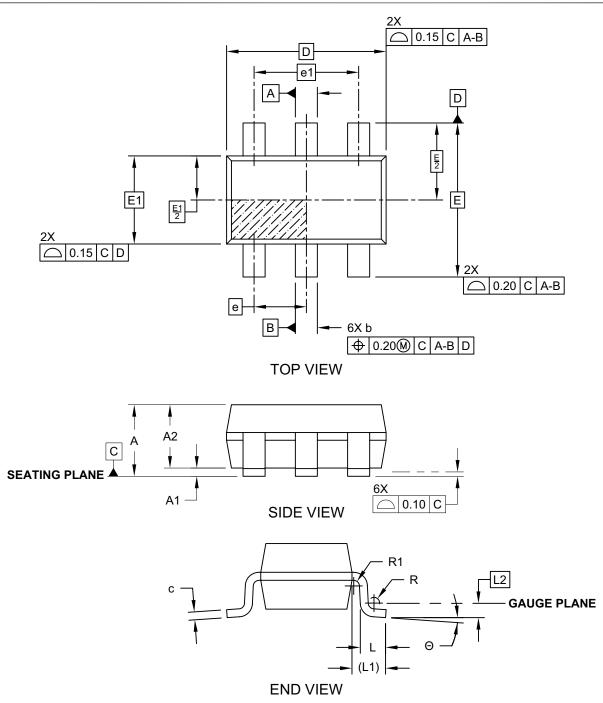
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2091B [OT]

6-Lead Plastic Small Outline Transistor (CH, CHY) [SOT-23]

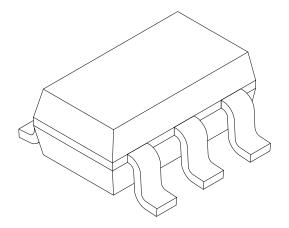




Microchip Technology Drawing C04-028C (CH) Sheet 1 of 2

6-Lead Plastic Small Outline Transistor (CH, CHY) [SOT-23]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	MILLIMETERS			
Dimension Limits		MIN	NOM	MAX	
Number of Leads	Ν	6			
Pitch	е		0.95 BSC		
Outside lead pitch	e1	1.90 BSC			
Overall Height	Α	0.90 - 1.4			
Molded Package Thickness	A2	0.89	1.15	1.30	
Standoff	A1	0.00	-	0.15	
Overall Width	E	2.80 BSC			
Molded Package Width	E1	1.60 BSC			
Overall Length	D	2.90 BSC			
Foot Length	L	0.30	0.45	0.60	
Footprint	L1	0.60 REF			
Seating Plane to Gauge Plane	L1	0.25 BSC			
Foot Angle	¢	0°	-	10°	
Lead Thickness	С	0.08	-	0.26	
Lead Width	b	0.20	-	0.51	

Notes:

1. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.25mm per side.

2. Dimensioning and tolerancing per ASME Y14.5M

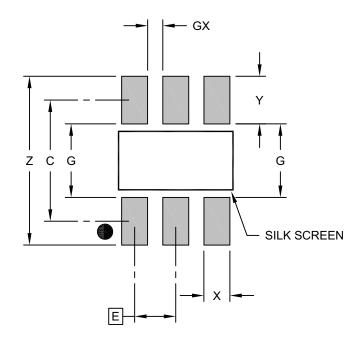
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-028C (CH) Sheet 2 of 2

6-Lead Plastic Small Outline Transistor (CH, CHY) [SOT-23]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS			
Dimension Limits		MIN	NOM	MAX	
Contact Pitch	E	0.95 BSC			
Contact Pad Spacing	С		2.80		
Contact Pad Width (X3)	X			0.60	
Contact Pad Length (X3)	Y			1.10	
Distance Between Pads	G	1.70			
Distance Between Pads	GX	0.35			
Overall Width	Z			3.90	

Notes:

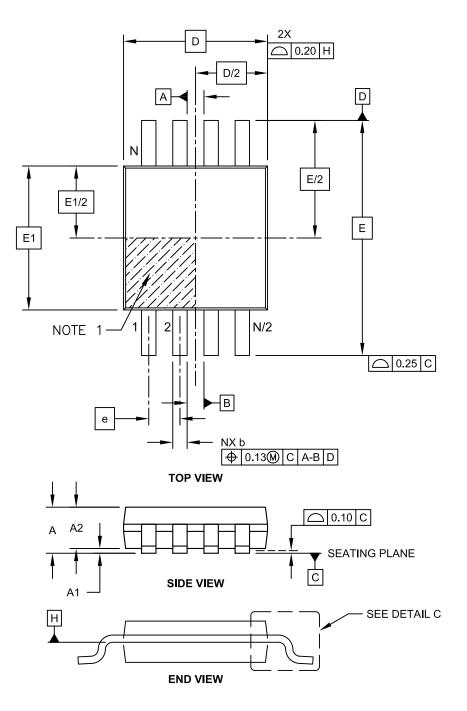
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2028B (CH)

8-Lead Plastic Micro Small Outline Package (MS) [MSOP]

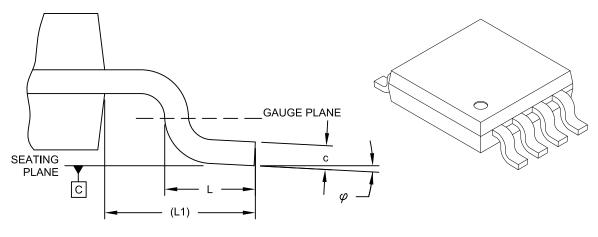
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-111C Sheet 1 of 2

8-Lead Plastic Micro Small Outline Package (MS) [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



DETAIL C

	MILLIMETERS				
Dimension Limits		MIN	NOM	MAX	
Number of Pins	И	8			
Pitch	e	0.65 BSC			
Overall Height	A	1.10			
Molded Package Thickness	A2	0.75	0.85	0.95	
Standoff	A1	0.00	-	0.15	
Overall Width	Ш	4.90 BSC			
Molded Package Width	E1	3.00 BSC			
Overall Length	D	3.00 BSC			
Foot Length	L	0.40	0.60	0.80	
Footprint	L1	0.95 REF			
Foot Angle	φ	0°	-	8°	
Lead Thickness	c	0.08	-	0.23	
Lead Width	b	0.22	-	0.40	

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

 Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.

protrusions shall not exceed 0.15mm per side. 3. Dimensioning and tolerancing per ASME Y14.5M.

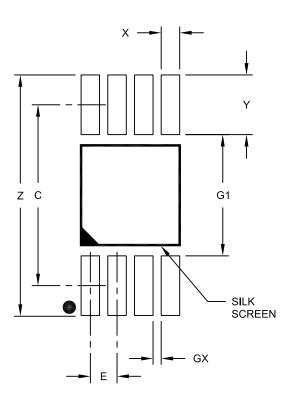
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-111C Sheet 2 of 2

8-Lead Plastic Micro Small Outline Package (MS) [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units		MILLIMETERS			
Dimensior	Dimension Limits		NOM	MAX		
Contact Pitch	E	E 0.65 BSC				
Contact Pad Spacing	С	4.40				
Overall Width	Z			5.85		
Contact Pad Width (X8)	X1			0.45		
Contact Pad Length (X8)	Y1			1.45		
Distance Between Pads	G1	2.95				
Distance Between Pads	GX	0.20				

Notes:

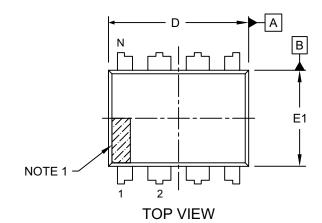
1. Dimensioning and tolerancing per ASME Y14.5M

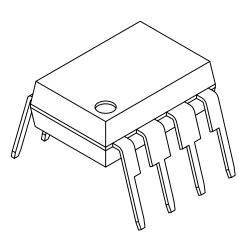
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

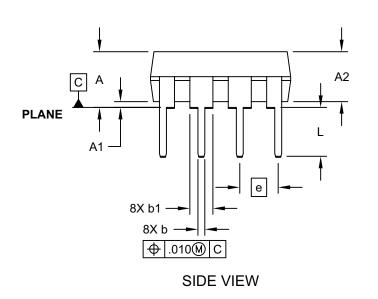
Microchip Technology Drawing No. C04-2111A

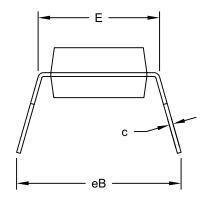
8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging







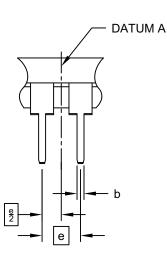


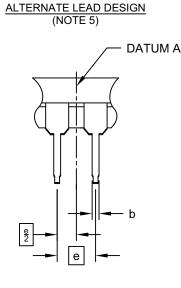
END VIEW

Microchip Technology Drawing No. C04-018-P Rev E Sheet 1 of 2

8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging





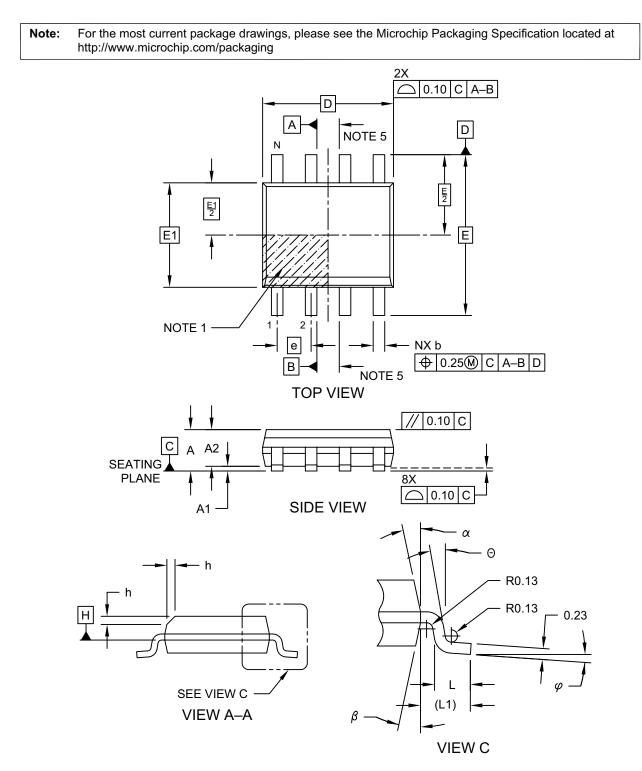
Units		INCHES			
Dimension Limits		MIN	NOM	MAX	
Number of Pins	N	8			
Pitch	е	.100 BSC			
Top to Seating Plane	Α	-	-	.210	
Molded Package Thickness	A2	.115	.130	.195	
Base to Seating Plane	A1	.015	-	-	
Shoulder to Shoulder Width	E	.290	.310	.325	
Molded Package Width	E1	.240	.250	.280	
Overall Length	D	.348	.365	.400	
Tip to Seating Plane	L	.115	.130	.150	
Lead Thickness	С	.008	.010	.015	
Upper Lead Width	b1	.040	.060	.070	
Lower Lead Width	b	.014	.018	.022	
Overall Row Spacing §	eВ	-	-	.430	

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. § Significant Characteristic
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
- Dimensioning and tolerancing per ASME Y14.5M BSC: Basic Dimension. Theoretically exact value shown without tolerances.
- 5. Lead design above seating plane may vary, based on assembly vendor.

Microchip Technology Drawing No. C04-018-P Rev E Sheet 2 of 2

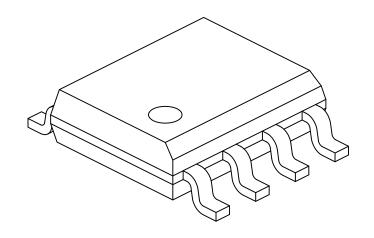
8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]



Microchip Technology Drawing No. C04-057-SN Rev E Sheet 1 of 2

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS			
Dimension Limits		MIN	NOM	MAX	
Number of Pins	N	8			
Pitch	е		1.27 BSC		
Overall Height	Α	-	-	1.75	
Molded Package Thickness	A2	1.25	-	-	
Standoff §	A1	0.10	-	0.25	
Overall Width	E	6.00 BSC			
Molded Package Width	E1	3.90 BSC			
Overall Length	D	4.90 BSC			
Chamfer (Optional)	h	0.25 - 0.50			
Foot Length	L	0.40	-	1.27	
Footprint	L1	1.04 REF			
Foot Angle	φ	0°	-	8°	
Lead Thickness	С	0.17	-	0.25	
Lead Width	b	0.31	-	0.51	
Mold Draft Angle Top	α	5°	-	15°	
Mold Draft Angle Bottom	β	5°	-	15°	

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. § Significant Characteristic

3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.

4. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

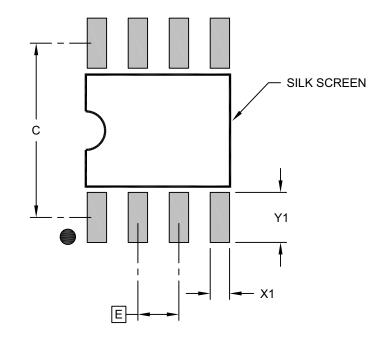
REF: Reference Dimension, usually without tolerance, for information purposes only.

5. Datums A & B to be determined at Datum H.

Microchip Technology Drawing No. C04-057-SN Rev E Sheet 2 of 2

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units		MILLIMETERS		
Dimension	Dimension Limits		NOM	MAX	
Contact Pitch	E		1.27 BSC		
Contact Pad Spacing	С		5.40		
Contact Pad Width (X8)	X1			0.60	
Contact Pad Length (X8)	Y1			1.55	

Notes:

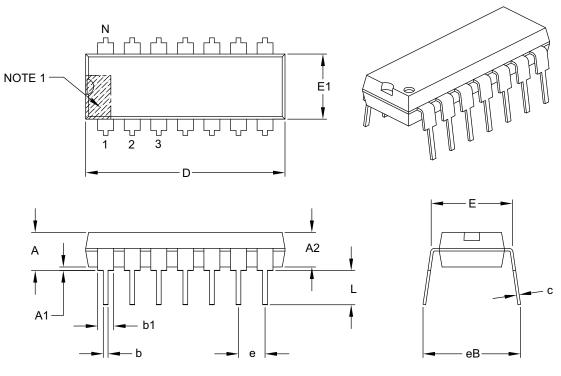
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-2057-SN Rev E

14-Lead Plastic Dual In-Line (P) – 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		INCHES	
Dimensio	n Limits	MIN	NOM	MAX
Number of Pins	Ν	14		
Pitch	е		.100 BSC	
Top to Seating Plane	Α	-	-	.210
Molded Package Thickness	A2	.115	.130	.195
Base to Seating Plane	A1	.015	-	-
Shoulder to Shoulder Width	Е	.290	.310	.325
Molded Package Width	E1	.240	.250	.280
Overall Length	D	.735	.750	.775
Tip to Seating Plane	L	.115	.130	.150
Lead Thickness	с	.008	.010	.015
Upper Lead Width	b1	.045	.060	.070
Lower Lead Width	b	.014	.018	.022
Overall Row Spacing §	eB	-	-	.430

Notes:

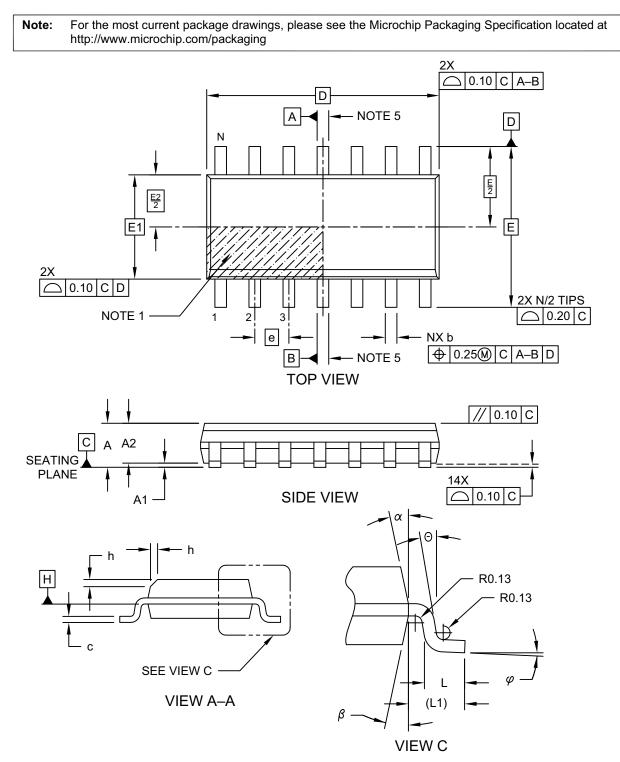
1. Pin 1 visual index feature may vary, but must be located with the hatched area.

- 2. § Significant Characteristic.
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-005B

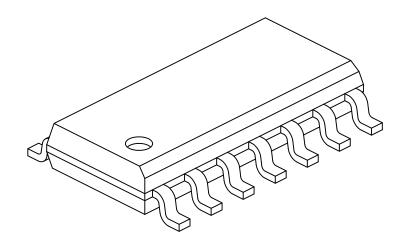
14-Lead Plastic Small Outline (SL) - Narrow, 3.90 mm Body [SOIC]



Microchip Technology Drawing No. C04-065-SL Rev D Sheet 1 of 2

14-Lead Plastic Small Outline (SL) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limi		MIN	NOM	MAX
Number of Pins	N		14	
Pitch	е		1.27 BSC	
Overall Height	Α	-	-	1.75
Molded Package Thickness	A2	1.25	-	-
Standoff §	A1	0.10	-	0.25
Overall Width	E	6.00 BSC		
Molded Package Width	E1	3.90 BSC		
Overall Length	D	8.65 BSC		
Chamfer (Optional)	h	0.25	-	0.50
Foot Length	L	0.40	-	1.27
Footprint	L1	1.04 REF		
Lead Angle	Θ	0°	-	-
Foot Angle	φ	0°	-	8°
Lead Thickness	С	0.10 - 0.25		0.25
Lead Width	b	0.31	-	0.51
Mold Draft Angle Top	α	5°	-	15°
Mold Draft Angle Bottom	β	5°	-	15°

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. § Significant Characteristic

- Dimension D does not include mold flash, protrusions or gate burrs, which shall not exceed 0.15 mm per end. Dimension E1 does not include interlead flash or protrusion, which shall not exceed 0.25 mm per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.

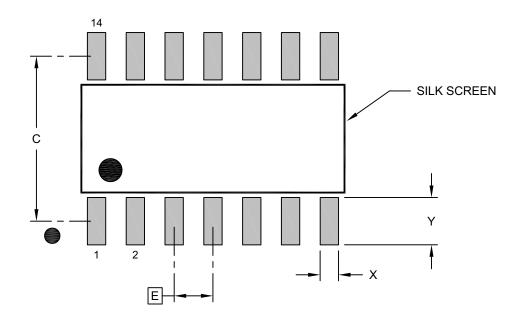
REF: Reference Dimension, usually without tolerance, for information purposes only.

5. Datums A & B to be determined at Datum H.

Microchip Technology Drawing No. C04-065-SL Rev D Sheet 2 of 2

14-Lead Plastic Small Outline (SL) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units		MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX	
Contact Pitch	Е		1.27 BSC		
Contact Pad Spacing	С		5.40		
Contact Pad Width (X14)	Х			0.60	
Contact Pad Length (X14)	Y			1.55	

Notes:

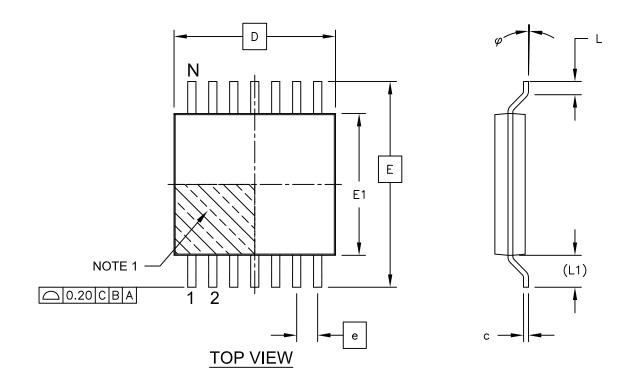
1. Dimensioning and tolerancing per ASME Y14.5M

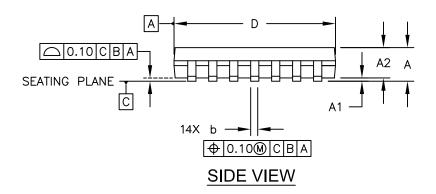
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2065-SL Rev D

14-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging

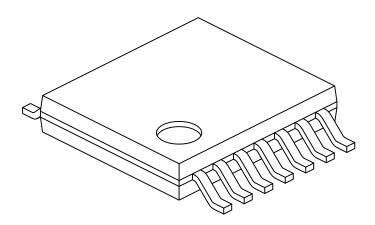




Microchip Technology Drawing C04-087C Sheet 1 of 2

14-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	Ν	MILLIMETER	S
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		14	
Pitch	е		0.65 BSC	_
Overall Height	A	-	-	1.20
Molded Package Thickness	A2	0.80	1.00	1.05
Standoff	A1	0.05	-	0.15
Overall Width	E	6.40 BSC		-
Molded Package Width	E1	4.30 4.40 4.50		4.50
Molded Package Length	D	4.90	5.00	5.10
Foot Length	L	0.45	0.60	0.75
Footprint	(L1)	1.00 REF		
Foot Angle	φ	0°	-	8°
Lead Thickness	С	0.09	-	0.20
Lead Width	b	0.19	-	0.30

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

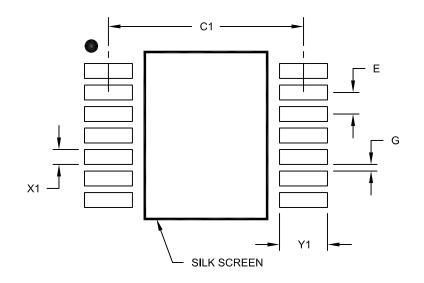
- 2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
- 3. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances. REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing No. C04-087C Sheet 2 of 2

14-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units		MILLIMETERS		
Dimension	Dimension Limits		NOM	MAX	
Contact Pitch	E	0.65 BSC			
Contact Pad Spacing	C1		5.90		
Contact Pad Width (X14)	X1			0.45	
Contact Pad Length (X14)	Y1			1.45	
Distance Between Pads	G	0.20			

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2087A

APPENDIX A: REVISION HISTORY

Revision E (November 2019)

The following is the list of modifications:

1. Updated Section 6.0 "Packaging Information".

Revision D (March 2013)

The following is the list of modifications:

- 1. Updated the boards list in Section 5.4 "Analog Demonstration and Evaluation Boards".
- 2. Removed the Mindi[™] Circuit Designer & Simulator section.
- Updated the E-Temp Code value for the 5-Lead SOT-23 package in Section 6.0 "Packaging Information".

Revision C (February 2008)

The following is the list of modifications:

- 1. Updated Figure 2-4 and Figure 2-5.
- 2. Updated trademark and Sales listing pages.
- 3. Expanded this op amp family:
- 4. Added the SOT-23-6 package for the MCP6043 op amp with Chip Select.
- 5. Added Extended Temperature (-40°C to +125°C) parts.
- 6. Expanded Analog Input Absolute Max Voltage Range (applies retroactively).
- 7. Expanded operating V_{DD} to a maximum of 6.0V.
- Section 1.0 "Electrical Characteristics" updated.
- Section 2.0 "Typical Performance Curves" updated.
- 10. Section 3.0 "Pin Descriptions" added.
- 11. Section 4.0"ApplicationsInformation" added.
- 12. Added Section 4.7 "Unused Op Amps".
- 13. Updated input stage explanation.
- 14. Section 5.0 "Design Aids" updated.
- 15. Section 6.0 "Packaging Information" updated.
- 16. Added SOT-23-6 package.
- 17. Corrected package marking information.
- 18. Appendix A: "Revision History" added.

Revision B (June 2002)

The following is the list of modifications.

· Undocumented changes.

Revision A (August 2001)

· Original data sheet release.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	<u> </u>	Examples:		
•	erature Package nge	 a) MCP6041-I/P: Industrial Temperature, 8LD PDIP package. b) MCP6041T-E/OT: Tape and Reel, Extended Temperature, 5LD SOT-23 package. 		
Device:	MCP6041: Single Op Amp MCP6041T Single Op Amp (Tape and Reel for SOT-23, SOIC, MSOP) MCP6042 Dual Op Amp MCP6042T Dual Op Amp (Tape and Reel for SOIC and MSOP) MCP6043 Single Op Amp w/ Chip Select MCP6043T Single Op Amp w/ Chip Select (Tape and Reel for SOT-23, SOIC, MSOP) MCP6044T Quad Op Amp MCP6044T Quad Op Amp (Tape and Reel for SOIC and TSSOP)	 a) MCP6042-I/SN: Industrial Temperature, 8LD SOIC package. b) MCP6042T-E/MS: Tape and Reel, Extended Temperature, 8LD MSOP package. a) MCP6043-I/P: Industrial Temperature, 8LD PDIP package. b) MCP6043T-E/CH: Tape and Reel, Extended Temperature, 6LD SOT-23 package. 		
Temperature Range:	$I = -40^{\circ}C \text{ to } +85^{\circ}C$ $E = -40^{\circ}C \text{ to } +125^{\circ}C$	 a) MCP6044-I/SL: Industrial Temperature, 14LD SOIC package. b) MCP6044T-E/ST: Tape and Reel, Extended Temperature, 14LD TSSOP package. 		
Package:	 CH = Plastic Small Outline Transistor (SOT-23), 6-lead (Tape and Reel - MCP6043 only) MS = Plastic Micro Small Outline (MSOP), 8-lead OT = Plastic Small Outline Transistor (SOT-23), 5-lead (Tape and Reel - MCP6041 only) P = Plastic DIP (300 mil Body), 8-lead, 14-lead SL = Plastic SOIC (150 mil Body), 14-lead SN = Plastic TSSOP (4.4 mm Body), 14-lead 			

NOTES:

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